



Low-Voltage, Sub-Ohm, SPDT Analog Switch

FEATURES

- Low Voltage Operation (1.6 V to 3.6 V)
- Low On-Resistance - $r_{DS(on)}$: 0.44 Ω Typ.
- Fast Switching - t_{ON} : 25 ns, t_{OFF} : 14 ns
- Low Leakage
- TTL/CMOS Compatible
- 6-Pin SC-70 Package

BENEFITS

- Reduced Power Consumption
- Simple Logic Interface
- High Accuracy
- Reduce Board Space

APPLICATIONS

- Cellular Phones
- Communication Systems
- Portable Test Equipment
- Battery Operated Systems
- Sample and Hold Circuits

DESCRIPTION

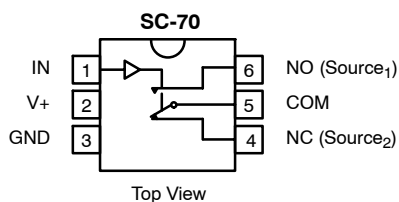
The DG2711 is a sub-ohm single-pole/double-throw monolithic CMOS analog switch designed for high performance switching of analog signals. Combining low power, high speed (t_{ON} : 25 ns, t_{OFF} : 14 ns), low on-resistance ($r_{DS(on)}$: 0.44 Ω) and small physical size (SC70), the DG2711 is ideal for portable and battery powered applications requiring high performance and efficient use of board space.

The DG2711 is built on Vishay Siliconix's low voltage submicron CMOS process. An epitaxial layer prevents latchup. Break-before-make is guaranteed for DG2711.

Each switch conducts equally well in both directions when on, and blocks up to the power supply level when off.

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with the lead (Pb)-free device terminations. For analog switching products manufactured with 100% matte tin device terminations, the lead (Pb)-free "—E3" suffix is being used as a designator.

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



Device Marking: E8xx

TRUTH TABLE

Logic	NC	NO
0	ON	OFF
1	OFF	ON

ORDERING INFORMATION

Temp Range	Package	Part Number
-40 to 85°C	SC70-6	DG2711DL-T1—E3



ABSOLUTE MAXIMUM RATINGS

Reference to GND

V+ -0.3 to +4 V

IN, COM, NC, NO^a -0.3 to (V+ + 0.3 V)Continuous Current (NO, NC and COM Pins) ± 200 mAPeak Current ± 300 mA
(Pulsed at 1 ms, 10% duty cycle)

Storage Temperature (D Suffix) -65 to 150°C

Power Dissipation (Packages)^b

6-Pin SO70° 250 mW

Notes:

- Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- All leads welded or soldered to PC Board.
- Derate 3.1 mW/°C above 70°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

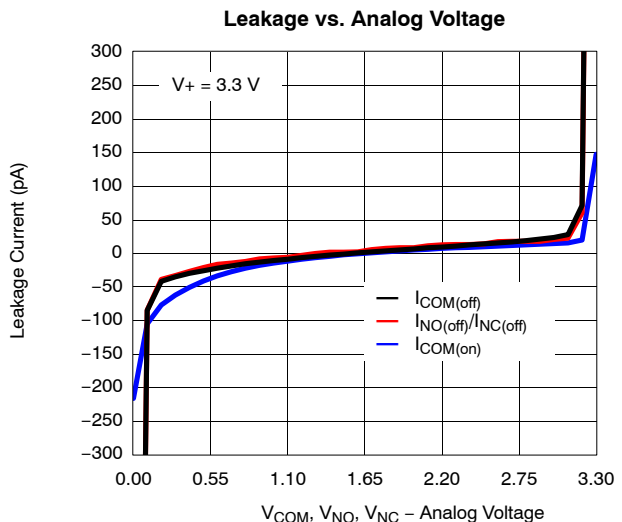
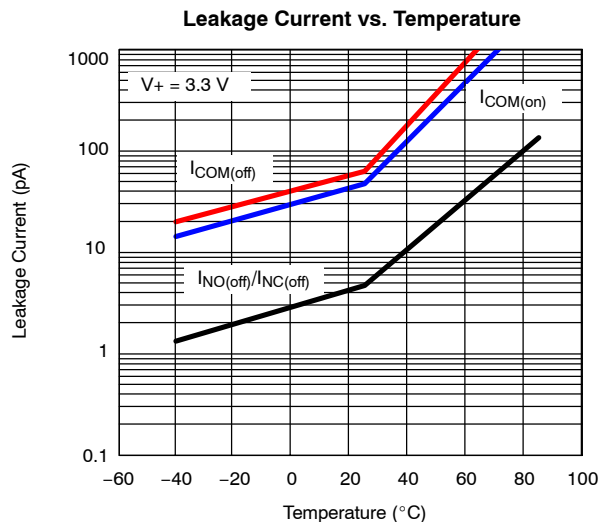
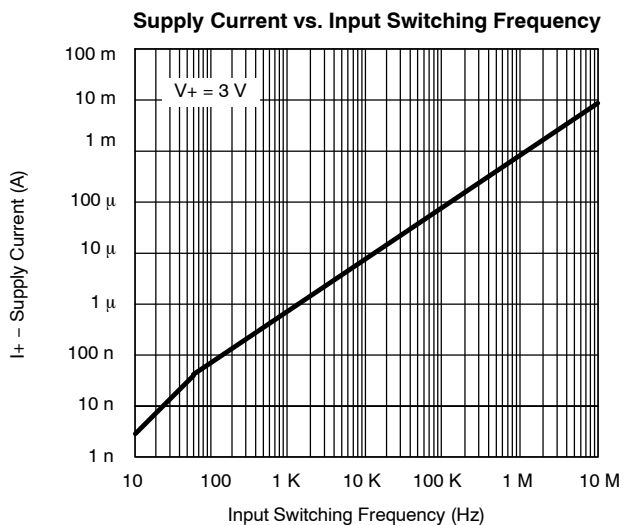
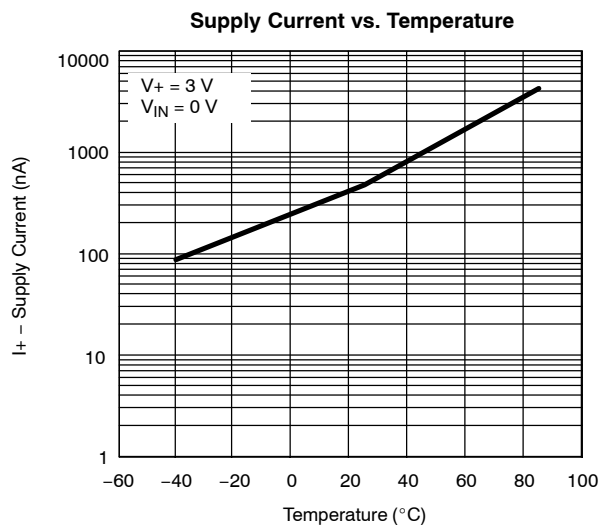
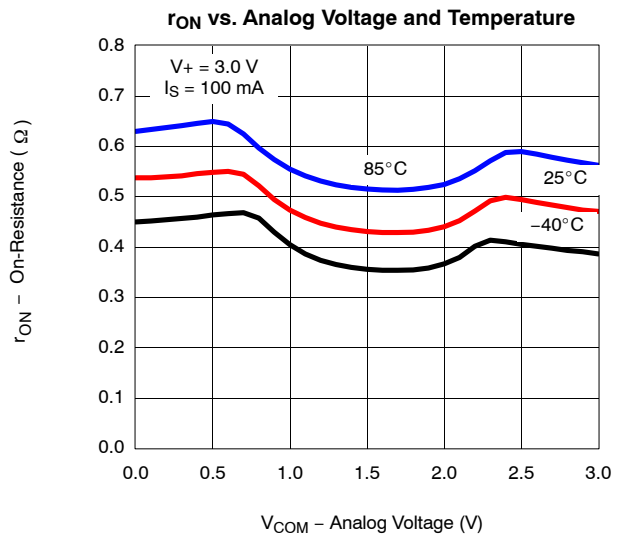
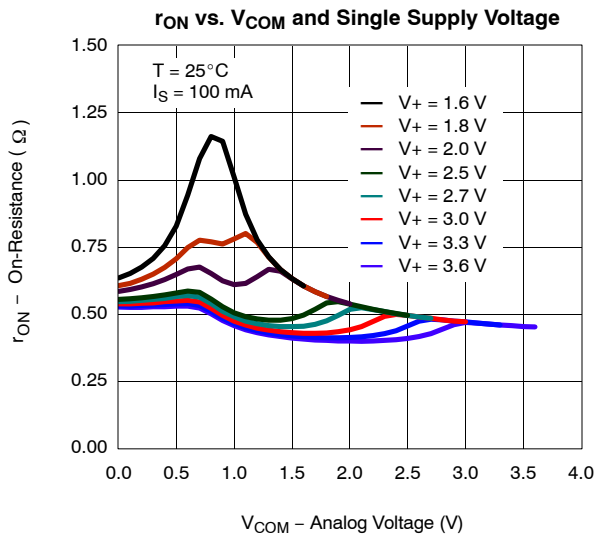
SPECIFICATIONS (V+ = 1.8 V)							
Parameter	Symbol	Test Conditions Otherwise Unless Specified V+ = 1.8 V, ± 10%, VIN = 0.4 or 1.0 V ^e	Temp ^a	Limits −40 to 85°C			Unit
				Min ^b	Typ ^c	Max ^b	
Analog Switch							
Analog Signal Range ^d	VNO, VNC, VCOM		Full	0		V+	V
On-Resistance	rON	V+ = 1.8 V, VCOM = 0.9 V, INO, INC = 100 mA	Room Full		0.8	2.0 2.5	Ω
Switch Off Leakage Current ^f	INO(off), INC(off)	V+ = 2.2 V VNO, VNC = 0.2 V/2.0 V, VCOM = 2.0 V/0.2 V	Room Full ^d	−1 −10		1 10	nA
	ICOM(off)		Room Full ^d	−1 −10		1 10	
Channel-On Leakage Current ^f	ICOM(on)	V+ = 2.2 V, VNO, VNC = VCOM = 0.2 V/2.0 V	Room Full ^d	−1 −10		1 10	
Digital Control							
Input High Voltage	VINH		Full	1.0			V
Input Low Voltage	VINL		Full			0.4	
Input Capacitance ^d	Cin		Full		5		pF
Input Current ^f	IINL or IINH	VIN = 0 or V+	Full	−1		1	μA
Dynamic Characteristics							
Turn-On Time ^d	tON	VNO or VNC = 1.5 V, RL = 300 Ω, CL = 35 pF Figures 1 and 2	Room Full ^d		36	60 62	ns
Turn-Off Time ^d	tOFF		Room Full ^d		22	42 44	
Break-Before-Make Time ^d	td		Room	3			
Charge Injection ^d	QINJ	CL = 1 nF, VGEN = 0 V, RGEN = 0 Ω, Figure 3	Room		20		pC
Off-Isolation ^d	OIRR	RL = 50 Ω, CL = 5 pF, f = 1 MHz	Room		−56		dB
Crosstalk ^d	XTALK		Room		−56		
NO, NC Off Capacitance ^d	CNO(off), CNC(off)	VIN = 0 or V+, f = 1 MHz	Room		73		pF
Channel-On Capacitance ^d	CON		Room		167		

**SPECIFICATIONS (V₊ = 3.0 V)**

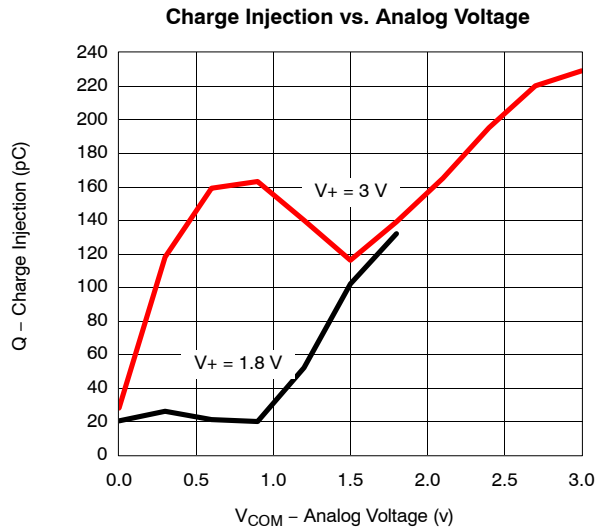
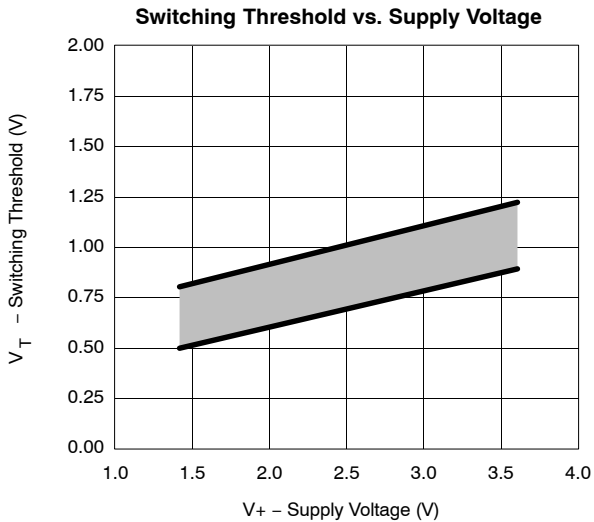
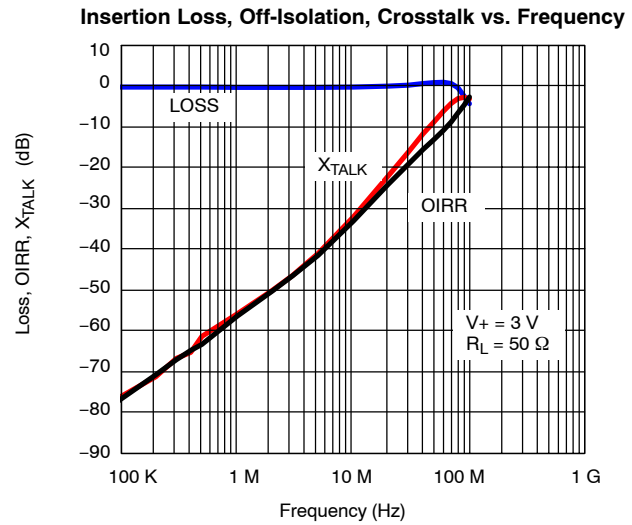
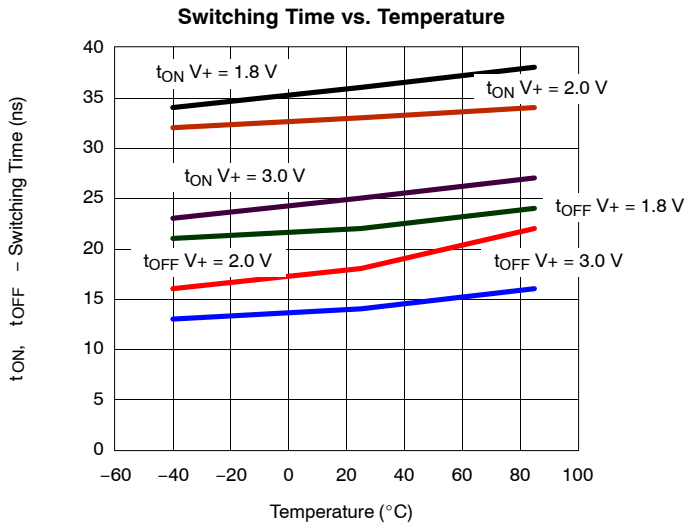
Parameter	Symbol	Test Conditions Otherwise Unless Specified V+ = 3 V, ±10%, VIN = 0.5 or 1.4 V ^e	Temp ^a	Limits –40 to 85°C			Unit
				Min ^b	Typ ^c	Max ^b	
Analog Switch							
Analog Signal Range ^d	VNO, VNC, VCOM		Full	0		V+	V
On-Resistance	rON	V+ = 2.7 V, VCOM = 1.5 V, INO INC = 100 mA	Room Full		0.44	0.6 0.7	Ω
rON Flatness	rON Flatness	V+ = 2.7 V, VCOM = 0.6 V, 1.5 V, INO INC = 100 mA	Room		0.14	0.2	
rON Match	ΔrON	V+ = 2.7 V, VCOM = 1.5 V, INO, INC = 100 mA	Room			0.07	
Switch Off Leakage Current	INO(off), INC(off)	V+ = 3.3 V VNO, VNC = 0.3 V/3 V, VCOM = 3 V/0.3 V	Room Full	–1 –10		1 10	nA
	ICOM(off)		Room Full	–1 –10		1 10	
Channel-On Leakage Current	ICOM(on)	V+ = 3.3 V, VNO, VNC = VCOM = 0.3 V/3 V	Room Full	–1 –10		1 10	
Digital Control							
Input High Voltage	VINH		Full	1.4			V
Input Low Voltage	VINL		Full			0.5	
Input Capacitance ^d	Cin		Full		5		pF
Input Current ^f	IINL or IINH	VIN = 0 or V+	Full	–1		1	μA
Dynamic Characteristics							
Turn-On Time	tON	VNO or VNC = 1.5 V, RL = 300 Ω, CL = 35 pF Figure 1 and 2	Room Full		25	46 48	ns
Turn-Off Time	tOFF		Room Full		14	38 40	
Break-Before-Make Time	t _d		Room	1			
Charge Injection ^d	QINJ	CL = 1 nF, VGEN = 0 V, RGEN = 0 Ω, Figure 3	Room		28		pC
Off-Isolation ^d	OIRR	RL = 50 Ω, CL = 5 pF, f = 1 MHz	Room		–56		dB
Crosstalk ^d	XTALK		Room		–56		
NO, NC Off Capacitance ^d	CNO(off), CNC(off)	VIN = 0 or V+, f = 1 MHz	Room		70		pF
Channel-On Capacitance ^d	CON		Room		163		
Power Supply							
Power Supply Range	V+			1.6		3.6	V
Power Supply Current	I+	V+ = 3.6 V, VIN = 0 or V+			0.01	1.0	μA

Notes:

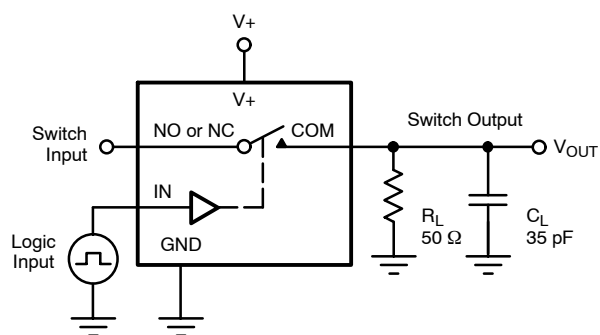
- Room = 25°C, Full = as determined by the operating suffix.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- Typical values are for design aid only, not guaranteed nor subject to production testing.
- Guarantee by design, nor subjected to production test.
- V_{IN} = input voltage to perform proper function.
- Guaranteed by 3-V leakage testing, not production tested.

TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)


TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

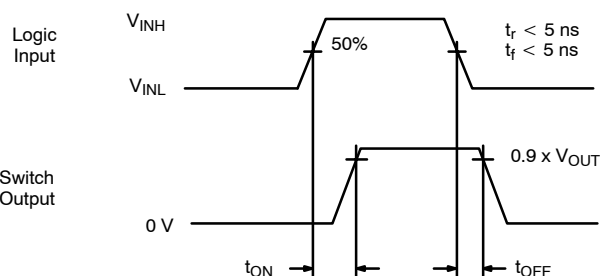


TEST CIRCUITS



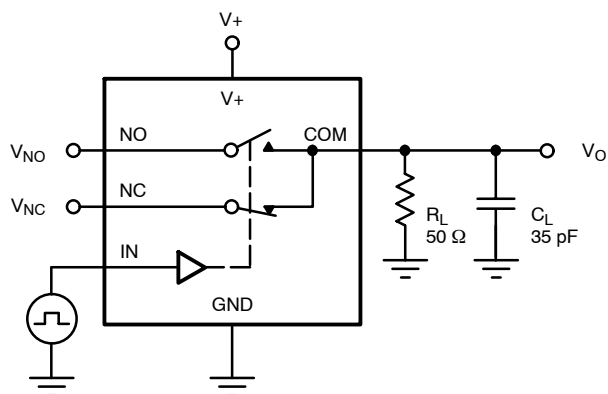
C_L (includes fixture and stray capacitance)

$$V_{OUT} = V_{COM} \left(\frac{R_L}{R_L + R_{ON}} \right)$$



Logic "1" = Switch On
Logic input waveforms inverted for switches that have the opposite logic sense.

FIGURE 1. Switching Time



C_L (includes fixture and stray capacitance)

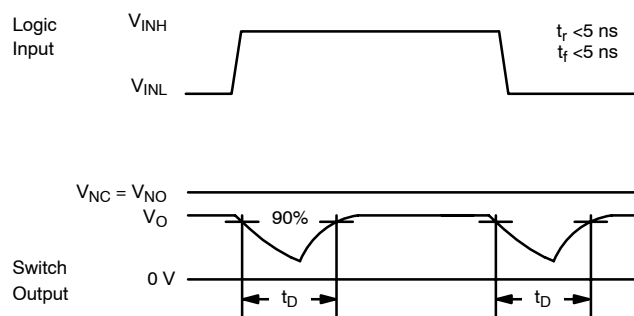
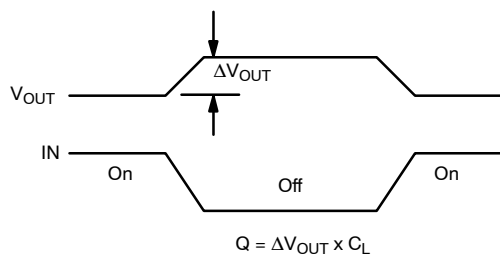
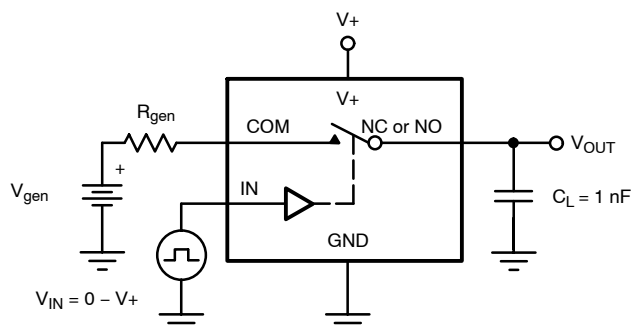


FIGURE 2. Break-Before-Make Interval



$Q = \Delta V_{OUT} \times C_L$
IN depends on switch configuration: input polarity determined by sense of switch.

FIGURE 3. Charge Injection

TEST CIRCUITS

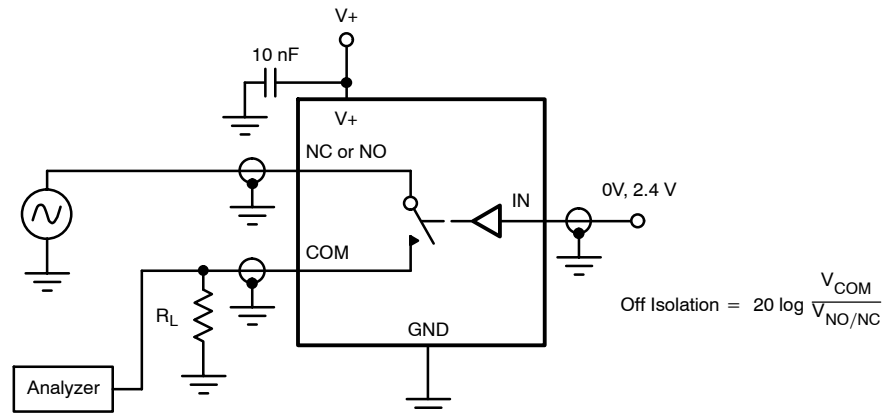


FIGURE 4. Off-Isolation

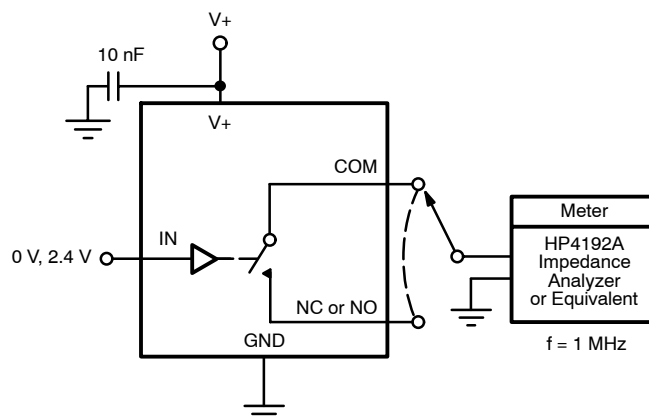


FIGURE 5. Channel Off/On Capacitance

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <http://www.vishay.com/ppg?73200>.



Notice

Specifications of the products displayed herein are subject to change without notice. Vishay Intertechnology, Inc., or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document. Except as provided in Vishay's terms and conditions of sale for such products, Vishay assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of Vishay products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Vishay for any damages resulting from such improper use or sale.